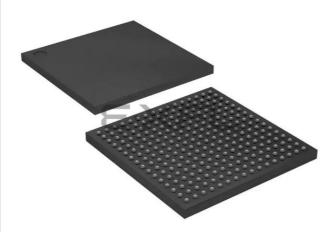
Intel - EP4CE10U14I7N Datasheet





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Details

Details	
Product Status	Active
Number of LABs/CLBs	645
Number of Logic Elements/Cells	10320
Total RAM Bits	423936
Number of I/O	179
Number of Gates	
Voltage - Supply	1.15V ~ 1.25V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	256-LFBGA
Supplier Device Package	256-UBGA (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep4ce10u14i7n

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A DC signal is equivalent to 100% duty cycle. For example, a signal that overshoots to 4.3 V can only be at 4.3 V for 65% over the lifetime of the device; for a device lifetime of 10 years, this amounts to 65/10ths of a year.

Symbol	Parameter	Condition (V)	Overshoot Duration as % of High Time	Unit	
		V ₁ = 4.20	100	%	
		V ₁ = 4.25	98	%	
			$V_1 = 4.30$	65	%
		V ₁ = 4.35	43	%	
Vi	AC Input Voltage	$V_1 = 4.40$	29	%	
	Voltago	$V_1 = 4.45$	20	%	
		$V_1 = 4.50$	13	%	
		V ₁ = 4.55	9	%	
		$V_1 = 4.60$	6	%	

Table 1–2. Maximum Allowed Overshoot During Transitions over a 10-Year Time Frame for Cyclone IV Devices

Figure 1–1 shows the methodology to determine the overshoot duration. The overshoot voltage is shown in red and is present on the input pin of the Cyclone IV device at over 4.3 V but below 4.4 V. From Table 1–2, for an overshoot of 4.3 V, the percentage of high time for the overshoot can be as high as 65% over a 10-year period. Percentage of high time is calculated as ([delta T]/T) × 100. This 10-year period assumes that the device is always turned on with 100% I/O toggle rate and 50% duty cycle signal. For lower I/O toggle rates and situations in which the device is in an idle state, lifetimes are increased.



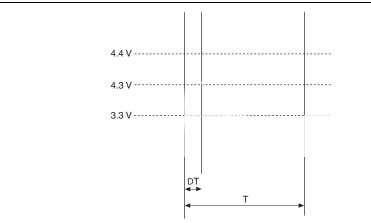


Table 1–3.	Recommended Operating Conditions for Cyclone IV E Devices ^{(1), (2}	⁹ (Part 2 of 2)
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{Diode}	Magnitude of DC current across PCI-clamp diode when enable	_	_		10	mA

Notes to Table 1–3:

 Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades.

(2) V_{CCI0} for all I/O banks must be powered up during device operation. All vCCA pins must be powered to 2.5 V (even when PLLs are not used) and must be powered up and powered down at the same time.

(3) V_{CC} must rise monotonically.

(4) V_{CCI0} powers all input buffers.

(5) The POR time for Standard POR ranges between 50 and 200 ms. Each individual power supply must reach the recommended operating range within 50 ms.

(6) The POR time for Fast POR ranges between 3 and 9 ms. Each individual power supply must reach the recommended operating range within 3 ms.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{ccint} <i>(3)</i>	Core voltage, PCIe hard IP block, and transceiver PCS power supply		1.16	1.2	1.24	V
V _{CCA} (1), (3)	PLL analog power supply	_	2.375	2.5	2.625	V
V _{CCD_PLL} <i>(2)</i>	PLL digital power supply	_	1.16	1.2	1.24	V
	I/O banks power supply for 3.3-V operation	—	3.135	3.3	3.465	V
/ _{CCINT} (3) / _{CCA} (1), (3) / _{CCD_PLL} (2) / _{CCIO} (3), (4) / _{CCC_CLKIN} (3), (5), (6)	I/O banks power supply for 3.0-V operation	—	2.85	3	3.15	V
\ <i>I</i> (3). (4)	I/O banks power supply for 2.5-V operation	_	2.375	2.5	2.625	V
V _{CCIO} (3), (4)	I/O banks power supply for 1.8-V operation	—	1.71	1.8	1.89	V
	I/O banks power supply for 1.5-V operation	—	1.425	1.5	2.625 1.24 3.465 3.15 2.625	V
	I/O banks power supply for 1.2-V operation	_	1.14	1.2	1.26	V
	Differential clock input pins power supply for 3.3-V operation	—	3.135	3.3	3.465	V
	Differential clock input pins power supply for 3.0-V operation	—	1.16 1.2 1.24 2.375 2.5 2.625 1.16 1.2 1.24 3.135 3.3 3.465 2.85 3 3.15 2.375 2.5 2.625 3.135 3.3 3.465 2.85 3 3.15 2.375 2.5 2.625 1.71 1.8 1.89 1.425 1.5 1.575 1.425 1.5 1.575 3.135 3.3 3.465 2.85 3 3.15 2.85 3 3.15 2.85 3 3.15 2.85 3 3.15 2.85 3 3.15 2.85 3 3.15 2.85 3 3.15 1.71 1.8 1.89 1.71 1.8 1.89 1.425 1.5 1.575	V		
V _{CC_CLKIN}	Differential clock input pins power supply for 2.5-V operation	—	2.375	2.5	2.625	V
(3), (5), (6)	Differential clock input pins power supply for 1.8-V operation	—	2.85 3 3.15 2.375 2.5 2.625 1.71 1.8 1.89 1.425 1.5 1.575 1.425 1.5 1.575 3.135 3.3 3.465 2.85 3 3.15 2.85 3 3.15 2.375 2.5 2.625 1.14 1.2 1.26 2.85 3 3.15 2.375 2.5 2.625 1.71 1.8 1.89 1.71 1.8 1.89 1.425 1.5 1.575 1.425 1.5 1.575 1.14 1.2 1.26	V		
	Differential clock input pins power supply for 1.5-V operation	—	1.425	1.5	1.575	V
	Differential clock input pins power supply for 1.2-V operation	—	1.14	1.2	1.26	V
V _{CCH_GXB}	Transceiver output buffer power supply	_	2.375	2.5	2.625	V

Table 1–4. Recommended Operating Conditions for Cyclone IV GX Devices (Part 1 of 2)

DC Characteristics

This section lists the I/O leakage current, pin capacitance, on-chip termination (OCT) tolerance, and bus hold specifications for Cyclone IV devices.

Supply Current

The device supply current requirement is the minimum current drawn from the power supply pins that can be used as a reference for power size planning. Use the Excel-based early power estimator (EPE) to get the supply current estimates for your design because these currents vary greatly with the resources used. Table 1–6 lists the I/O pin leakage current for Cyclone IV devices.

Table 1–6. I/O Pin Leakage Current for Cyclone IV Devices (1), (2)

Symbol	Parameter	Conditions	Device	Min	Тур	Max	Unit
I _I	Input pin leakage current	$V_{I} = 0 V \text{ to } V_{CCIOMAX}$	_	-10	_	10	μA
I _{OZ}	Tristated I/O pin leakage current	$V_0 = 0 V$ to $V_{CCIOMAX}$		-10		10	μΑ

Notes to Table 1-6:

(1) This value is specified for normal device operation. The value varies during device power-up. This applies for all V_{CCI0} settings (3.3, 3.0, 2.5, 1.8, 1.5, and 1.2 V).

(2) The 10 μ A I/O leakage current limit is applicable when the internal clamping diode is off. A higher current can be observed when the diode is on.

Bus Hold

The bus hold retains the last valid logic state after the source driving it either enters the high impedance state or is removed. Each I/O pin has an option to enable bus hold in user mode. Bus hold is always disabled in configuration mode.

Table 1–7 lists bus hold specifications for Cyclone IV devices.

 Table 1–7. Bus Hold Parameter for Cyclone IV Devices (Part 1 of 2)⁽¹⁾

		V _{CCI0} (V)												
Parameter	Condition	1.2		1	1.5 1.8		.8 2		.5	3.0		3.3		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Bus hold low, sustaining current	V _{IN} > V _{IL} (maximum)	8	_	12	_	30	_	50	_	70	_	70	_	μА
Bus hold high, sustaining current	V _{IN} < V _{IL} (minimum)	-8	_	-12	_	-30		-50	_	-70	_	-70	_	μΑ
Bus hold low, overdrive current	$0 V < V_{\rm IN} < V_{\rm CCI0}$	_	125		175	_	200	_	300		500		500	μA
Bus hold high, overdrive current	$0 \text{ V} < \text{V}_{\text{IN}} < \text{V}_{\text{CCIO}}$	_	-125	_	-175		-200		-300		-500		-500	μА

Example 1–1 shows how to calculate the change of 50- Ω I/O impedance from 25°C at 3.0 V to 85°C at 3.15 V.

Example 1–1. Impedance Change

$$\begin{split} \Delta R_V &= (3.15-3) \times 1000 \times -0.026 = -3.83 \\ \Delta R_T &= (85-25) \times 0.262 = 15.72 \\ \text{Because } \Delta R_V \text{ is negative,} \\ MF_V &= 1 \ / \ (3.83/100 + 1) = 0.963 \\ \text{Because } \Delta R_T \text{ is positive,} \\ MF_T &= 15.72/100 + 1 = 1.157 \\ MF &= 0.963 \times 1.157 = 1.114 \\ R_{\text{final}} &= 50 \times 1.114 = 55.71 \ \Omega \end{split}$$

Pin Capacitance

Table 1–11 lists the pin capacitance for Cyclone IV devices.

Symbol	Parameter	Typical – Quad Flat Pack (QFP)	Typical – Quad Flat No Leads (QFN)	Typical – Ball-Grid Array (BGA)	Unit
C _{IOTB}	Input capacitance on top and bottom I/O pins	7	7	6	pF
C _{IOLR}	Input capacitance on right I/O pins	7	7	5	pF
C_{LVDSLR}	Input capacitance on right I/O pins with dedicated LVDS output	8	8	7	pF
C _{VREFLR}	Input capacitance on right dual-purpose ${\tt VREF}$ pin when used as $V_{\sf REF}$ or user I/O pin	21	21	21	pF
C _{VREFTB}	Input capacitance on top and bottom dual-purpose ${\tt VREF}$ pin when used as $V_{\sf REF}$ or user I/O pin	23 <i>(3)</i>	23	23	pF
C _{CLKTB}	Input capacitance on top and bottom dedicated clock input pins	7	7	6	pF
C _{CLKLR}	Input capacitance on right dedicated clock input pins	6	6	5	pF

Notes to Table 1-11:

(1) The pin capacitance applies to FBGA, UBGA, and MBGA packages.

(2) When you use the vref pin as a regular input or output, you can expect a reduced performance of toggle rate and t_{CO} because of higher pin capacitance.

(3) C_{VREFTB} for the EP4CE22 device is 30 pF.

Schmitt Trigger Input

Cyclone IV devices support Schmitt trigger input on the TDI, TMS, TCK, nSTATUS, nCONFIG, nCE, CONF_DONE, and DCLK pins. A Schmitt trigger feature introduces hysteresis to the input signal for improved noise immunity, especially for signals with slow edge rate. Table 1–14 lists the hysteresis specifications across the supported V_{CCIO} range for Schmitt trigger inputs in Cyclone IV devices.

 Table 1–14.
 Hysteresis Specifications for Schmitt Trigger Input in Cyclone IV Devices

Symbol	Parameter	Conditions (V)	Minimum	Unit
		V _{CCI0} = 3.3	200	mV
V _{SCHMITT}	Hysteresis for Schmitt trigger	V _{CCI0} = 2.5	200	mV
	input	V _{CCI0} = 1.8	140	mV
		V _{CCI0} = 1.5	110	mV

I/O Standard Specifications

The following tables list input voltage sensitivities (V_{IH} and V_{IL}), output voltage (V_{OH} and V_{OL}), and current drive characteristics (I_{OH} and I_{OL}), for various I/O standards supported by Cyclone IV devices. Table 1–15 through Table 1–20 provide the I/O standard specifications for Cyclone IV devices.

1/0 Standard		V _{ccio} (V		V	_{IL} (V)	V	/ _{IH} (V)	V _{OL} (V)	V _{OH} (V)	I _{OL}	I _{OH}
I/O Standard	Min	Тур	Max	Min	Max	Min	Max	Max	Min	(mA) (4)	(mA) (4)
3.3-V LVTTL <i>(3)</i>	3.135	3.3	3.465	—	0.8	1.7	3.6	0.45	2.4	4	-4
3.3-V LVCMOS (3)	3.135	3.3	3.465		0.8	1.7	3.6	0.2	V _{CCI0} - 0.2	2	-2
3.0-V LVTTL (3)	2.85	3.0	3.15	-0.3	0.8	1.7	V _{CCI0} + 0.3	0.45	2.4	4	-4
3.0-V LVCMOS (3)	2.85	3.0	3.15	-0.3	0.8	1.7	V _{CCI0} + 0.3	0.2	$V_{CC10} - 0.2$	0.1	-0.1
2.5 V ⁽³⁾	2.375	2.5	2.625	-0.3	0.7	1.7	V _{CCI0} + 0.3	0.4	2.0	1	-1
1.8 V	1.71	1.8	1.89	-0.3	0.35 x V _{CCI0}	0.65 x V _{CCI0}	2.25	0.45	V _{CCI0} – 0.45	2	-2
1.5 V	1.425	1.5	1.575	-0.3	0.35 x V _{CCI0}	0.65 x V _{CCI0}	V _{CCI0} + 0.3	0.25 x V _{CCIO}	0.75 x V _{CCIO}	2	-2
1.2 V	1.14	1.2	1.26	-0.3	0.35 x V _{CCI0}	0.65 x V _{CCI0}	V _{CCI0} + 0.3	0.25 x V _{CCIO}	0.75 x V _{CCIO}	2	-2
3.0-V PCI	2.85	3.0	3.15		0.3 x V _{CCIO}	0.5 x V _{CCIO}	V _{CCI0} + 0.3	0.1 x V _{CCIO}	0.9 x V _{CCIO}	1.5	-0.5
3.0-V PCI-X	2.85	3.0	3.15	_	0.35 x V _{CCI0}	0.5 x V _{CCI0}	V _{CCI0} + 0.3	$0.1 \times V_{CCIO}$	$0.9 \times V_{CCIO}$	1.5	-0.5

Table 1–15. Single-Ended I/O Standard Specifications for Cyclone IV Devices (1), (2)

Notes to Table 1–15:

(1) For voltage-referenced receiver input waveform and explanation of terms used in Table 1–15, refer to "Glossary" on page 1–37.

(2) AC load CL = 10 pF

(3) For more information about interfacing Cyclone IV devices with 3.3/3.0/2.5-V LVTTL/LVCMOS I/O standards, refer to AN 447: Interfacing Cyclone III and Cyclone IV Devices with 3.3/3.0/2.5-V LVTTL/LVCMOS I/O Systems.

(4) To meet the loL and loH specifications, you must set the current strength settings accordingly. For example, to meet the **3.3-V LVTTL** specification (4 mA), set the current strength settings to 4 mA or higher. Setting at lower current strength may not meet the loL and loH specifications in the handbook.

I/O		V _{ccio} (V))		V _{REF} (V)			V _{TT} (V) ⁽²⁾	
Standard	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max
SSTL-2 Class I, II	2.375	2.5	2.625	1.19	1.25	1.31	V _{REF} – 0.04	V _{REF}	V _{REF} + 0.04
SSTL-18 Class I, II	1.7	1.8	1.9	0.833	0.9	0.969	V _{REF} – 0.04	V _{REF}	V _{REF} + 0.04
HSTL-18 Class I, II	1.71	1.8	1.89	0.85	0.9	0.95	0.85	0.9	0.95
HSTL-15 Class I, II	1.425	1.5	1.575	0.71	0.75	0.79	0.71	0.75	0.79
HSTL-12 Class I, II	1.14	1.2	1.26	0.48 x V _{CCI0} (3) 0.47 x V _{CCI0} (4)	$\begin{array}{c} 0.5 \mbox{ x } V_{\rm CC10} \ \ {}^{(3)} \\ 0.5 \mbox{ x } V_{\rm CC10} \ \ {}^{(4)} \end{array}$	$\begin{array}{l} 0.52 \times V_{\rm CCI0} \ {}^{(3)} \\ 0.53 \times V_{\rm CCI0} \ {}^{(4)} \end{array}$	_	0.5 x V _{CCIO}	_

Notes to Table 1–16:

(1) For an explanation of terms used in Table 1–16, refer to "Glossary" on page 1–37.

(2) $\,\,V_{TT}$ of the transmitting device must track V_{REF} of the receiving device.

(3) Value shown refers to DC input reference voltage, $V_{\text{REF(DC)}}.$

(4) Value shown refers to AC input reference voltage, $V_{\text{REF(AC)}}$.

Table 1-17.	Single-Ended SSTL and HST	L I/O Standards Signal S	Specifications for C	yclone IV Devices
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I/O	V _{IL(}	_(DC) (V)	VIII	_{I(DC)} (V)	V _{IL(}	_{AC)} (V)	VIH	_(AC) (V)	V _{OL} (V)	V _{oh} (V)	I _{OL}	I _{oh}
Standard	Min	Max	Min	Max	Min	Max	Min	Max	Max	Min	(mĀ)	(mÄ)
SSTL-2 Class I		V _{REF} – 0.18	V _{REF} + 0.18	_		V _{REF} – 0.35	V _{REF} + 0.35	—	V _{ττ} – 0.57	V _{TT} + 0.57	8.1	-8.1
SSTL-2 Class II	_	V _{REF} – 0.18	V _{REF} + 0.18	—	_	V _{REF} – 0.35	V _{REF} + 0.35	—	V _{TT} – 0.76	V _{TT} + 0.76	16.4	-16.4
SSTL-18 Class I	_	V _{REF} – 0.125	V _{REF} + 0.125	—	_	V _{REF} – 0.25	V _{REF} + 0.25	—	V _{TT} – 0.475	V _{TT} + 0.475	6.7	-6.7
SSTL-18 Class II	_	V _{REF} – 0.125	V _{REF} + 0.125	_	_	V _{REF} – 0.25	V _{REF} + 0.25	—	0.28	V _{CCI0} – 0.28	13.4	-13.4
HSTL-18 Class I	_	V _{REF} – 0.1	V _{REF} + 0.1	—	_	V _{REF} – 0.2	V _{REF} + 0.2	—	0.4	V _{CCI0} – 0.4	8	-8
HSTL-18 Class II	_	V _{REF} – 0.1	V _{REF} + 0.1	—	_	V _{REF} – 0.2	V _{REF} + 0.2	—	0.4	V _{CCIO} – 0.4	16	-16
HSTL-15 Class I	_	V _{REF} – 0.1	V _{REF} + 0.1	—	_	V _{REF} – 0.2	V _{REF} + 0.2	—	0.4	V _{CCIO} – 0.4	8	-8
HSTL-15 Class II	_	V _{REF} – 0.1	V _{REF} + 0.1	_	_	V _{REF} – 0.2	V _{REF} + 0.2	_	0.4	V _{CCI0} – 0.4	16	-16
HSTL-12 Class I	-0.15	V _{REF} - 0.08	V _{REF} + 0.08	V _{CCI0} + 0.15	-0.24	V _{REF} – 0.15	V _{REF} + 0.15	V _{CCI0} + 0.24	0.25 × V _{CCI0}	0.75 × V _{CCI0}	8	-8
HSTL-12 Class II	-0.15	V _{REF} – 0.08	V _{REF} + 0.08	V _{CCI0} + 0.15	-0.24	V _{REF} – 0.15	V _{REF} + 0.15	V _{CCI0} + 0.24	0.25 × V _{CCIO}	0.75 × V _{CCIO}	14	-14

• For more information about receiver input and transmitter output waveforms, and for other differential I/O standards, refer to the *I/O Features in Cyclone IV Devices* chapter.

Table 1–18. Differential SSTL I/O Standard Specifications for Cyclone IV Devices (1)

I/O Standard	v	V _{CCIO} (V)			_{I(DC)} (V)	$V_{X(AC)}(V) = V_{Swing(AC)} = V_{OX(AC)}(V)$				V _{OX(AC)} (V)			
	Min	Тур	Max	Min	Max	Min	Тур	Max	Min	Max	Min	Тур	Max
SSTL-2 Class I, II	2.375	2.5	2.625	0.36	V _{CCIO}	$V_{CCIO}/2 - 0.2$	_	V _{CCI0} /2 + 0.2	0.7	V _{CCI} 0	V _{CCIO} /2 – 0.125		V _{CCI0} /2 + 0.125
SSTL-18 Class I, II	1.7	1.8	1.90	0.25	V _{CCIO}	V _{CCIO} /2 – 0.175	_	V _{CCI0} /2 + 0.175	0.5	V _{CCI} 0	V _{CCIO} /2 – 0.125	_	V _{CCI0} /2 + 0.125

Note to Table 1–18:

(1) Differential SSTL requires a V_{REF} input.

Table 1–19. Differential HSTL I/O Standard Specifications for Cyclone IV Devices ⁽¹⁾

	V	V _{CC10} (V)			_{DC)} (V)	Vx	(V) (X)		V	CM(DC)	V)	V _{DIF(AC)} (V)	
I/O Standard	Min	Тур	Max	Min	Max	Min	Тур	Max	Min	Тур	Max	Mi n	Max
HSTL-18 Class I, II	1.71	1.8	1.89	0.2	_	0.85	—	0.95	0.85	—	0.95	0.4	_
HSTL-15 Class I, II	1.425	1.5	1.575	0.2	_	0.71	_	0.79	0.71	_	0.79	0.4	_
HSTL-12 Class I, II	1.14	1.2	1.26	0.16	V _{CCIO}	$0.48 \times V_{CCIO}$	_	0.52 x V _{CCI0}	0.48 x V _{CCIO}	_	0.52 x V _{CCI0}	0.3	0.48 x V _{CCI0}

Note to Table 1-19:

(1) Differential HSTL requires a V_{REF} input.

 Table 1–20. Differential I/O Standard Specifications for Cyclone IV Devices ⁽¹⁾ (Part 1 of 2)

I/O Standard		V _{CCIO} (V)			V _{ID} (mV)		V _{ICM} (V) <i>(2)</i>			V _{0D} (mV) ⁽³⁾			V _{os} (V) <i>(3)</i>		
i/U Stalluaru	Min	Тур	Max	Min	Max	Min	Condition	Max	Min	Тур	Max	Min	Тур	Max	
						0.05	$D_{MAX} \leq 500 \; Mbps$	1.80							
LVPECL (Row I/Os) (6)	2.375	2.5	2.625	100	_	0.55	$\begin{array}{l} 500 \text{ Mbps} \leq \text{ D}_{\text{MAX}} \\ \leq 700 \text{ Mbps} \end{array}$	1.80	_	—	_	—	—	_	
						1.05	D _{MAX} > 700 Mbps	1.55							
						0.05	$D_{MAX} \leq ~500~Mbps$	1.80							
LVPECL (Column I/Os) <i>(6)</i>	2.375	2.5	2.625	100		0.55	$\begin{array}{l} 500 \text{ Mbps} \leq \text{D}_{\text{MAX}} \\ \leq 700 \text{ Mbps} \end{array}$	1.80	_	—	_	_	_	_	
1/03/						1.05	D _{MAX} > 700 Mbps	1.55							
						0.05	$D_{MAX} \leq 500 \; Mbps$	1.80							
LVDS (Row I/Os)	2.375	2.5	2.625	100	_	0.55	$\begin{array}{l} 500 \text{ Mbps} \leq \text{D}_{\text{MAX}} \\ \leq \ 700 \text{ Mbps} \end{array}$	1.80	247	—	600	1.125	1.25	1.375	
						1.05	D _{MAX} > 700 Mbps	1.55							

Transceiver Performance Specifications

Table 1–21 lists the Cyclone IV GX transceiver specifications.

Table 1–21. Transceiver Specification for Cyclone IV GX Devices (Part 1 of 4)

Symbol/	0 and 111 and		C6			C7, I7			C 8		
Description	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Reference Clock						-		<u>.</u>		<u>.</u>	-
Supported I/O Standards		1.2 V F	PCML, 1.5	V PCML, 3	.3 V PCN	1L, Differe	ntial LVPE	CL, LVD	S, HCSL		
Input frequency from REFCLK input pins	_	50	_	156.25	50	_	156.25	50	_	156.25	MHz
Spread-spectrum modulating clock frequency	Physical interface for PCI Express (PIPE) mode	30	_	33	30	_	33	30	_	33	kHz
Spread-spectrum downspread	PIPE mode	_	0 to 0.5%	_	_	0 to -0.5%	_	_	0 to 0.5%	_	_
Peak-to-peak differential input voltage	_	0.1	_	1.6	0.1	_	1.6	0.1	_	1.6	V
V_{ICM} (AC coupled)	—		1100 ± 5	%		1100 ± 59	%		1100 ± 5	%	mV
V_{ICM} (DC coupled)	HCSL I/O standard for PCIe reference clock	250	_	550	250	_	550	250	_	550	mV
Transmitter REFCLK Phase Noise ⁽¹⁾	Frequency offset		_	-123	_	_	-123	_	_	-123	dBc/Hz
Transmitter REFCLK Total Jitter ⁽¹⁾	= 1 MHz – 8 MHZ		_	42.3	_	_	42.3	_	_	42.3	ps
R _{ref}			2000 ± 1%		_	2000 ± 1%	_	_	2000 ± 1%	_	Ω
Transceiver Clock											
cal_blk_clk clock frequency	_	10	_	125	10	_	125	10	_	125	MHz
fixedclk clock frequency	PCIe Receiver Detect	_	125	_	_	125	_	_	125	—	MHz
reconfig_clk clock frequency	Dynamic reconfiguration clock frequency	2.5/ 37.5 <i>(2)</i>	_	50	2.5/ 37.5 <i>(2)</i>	_	50	2.5/ 37.5 <i>(2)</i>	_	50	MHz
Delta time between reconfig_clk	_	_	_	2	_	_	2	_	_	2	ms
Transceiver block minimum power-down pulse width	_	_	1		_	1	_	_	1	—	μs

Symbol/	Conditions		C6			C7, I7				11	
Description	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Receiver					•	•		•	•		
Supported I/O Standards	1.4 V PCML, 1.5 V PCML, 2.5 V PCML, LVPECL, LVDS										
Data rate (F324 and smaller package) ⁽¹⁵⁾	_	600	_	2500	600	_	2500	600	_	2500	Mbps
Data rate (F484 and larger package) ⁽¹⁵⁾	—	600	_	3125	600	_	3125	600	_	2500	Mbps
Absolute V _{MAX} for a receiver pin <i>(3)</i>	—	_	_	1.6	_	_	1.6	_	_	1.6	V
Operational V _{MAX} for a receiver pin	—	_	_	1.5	_	_	1.5	_	_	1.5	V
Absolute V _{MIN} for a receiver pin	_	-0.4	_	_	-0.4	_	_	-0.4	_	_	V
Peak-to-peak differential input voltage V _{ID} (diff p-p)	V _{ICM} = 0.82 V setting, Data Rate = 600 Mbps to 3.125 Gbps	0.1	_	2.7	0.1	_	2.7	0.1	_	2.7	V
V _{ICM}	V _{ICM} = 0.82 V setting	_	820 ± 10%	_	_	820 ± 10%	_	_	820 ± 10%	_	mV
Differential on-chip	100– Ω setting		100	—	_	100		_	100	—	Ω
termination resistors	150– Ω setting	—	150	_	_	150		_	150	—	Ω
Differential and common mode return loss	PIPE, Serial Rapid I/O SR, SATA, CPRI LV, SDI, XAUI					Compliant	Ľ				_
Programmable ppm detector ⁽⁴⁾	_				± 62.5	, 100, 128 250, 300					ppm
Clock data recovery (CDR) ppm tolerance (without spread-spectrum clocking enabled)				±300 <i>(5)</i> , ±350 <i>(6)</i> , <i>(7)</i>			±300 (5), ±350 (6), (7)		_	±300 (5), ±350 (6), (7)	ppm
CDR ppm tolerance (with synchronous spread-spectrum clocking enabled) ⁽⁸⁾	_	_	_	350 to 5350 (7), (9)	_		350 to 5350 (7), (9)	_		350 to 5350 (7), (9)	ppm
Run length	—		80		—	80	_	—	80		UI
	No Equalization		_	1.5	—	_	1.5	—	_	1.5	dB
Programmable	Medium Low		_	4.5	_	_	4.5	_		4.5	dB
equalization	Medium High		_	5.5	—	_	5.5	—	_	5.5	dB
	High	—		7	-	_	7	-	_	7	dB

Table 1–21.	Transceiver S	necification fo	r Cyclone	IV GX Devices	(Part 2 of 4)
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Table 1–21. Transceiver Specification for Cyclone IV GX Devices (Part 4 of 4)

Symbol/	Conditions		C6			C7, 17			C 8		Unit
Description	Conultions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	UIIIL
PLD-Transceiver Inte	rface										
Interface speed (F324 and smaller package)	_	25	_	125	25	_	125	25	_	125	MHz
Interface speed (F484 and larger package)	_	25	_	156.25	25	_	156.25	25	_	156.25	MHz
Digital reset pulse width	_		Minimum is 2 parallel clock cycles								

Notes to Table 1–21:

(1) This specification is valid for transmitter output jitter specification with a maximum total jitter value of 112 ps, typically for 3.125 Gbps SRIO and XAUI protocols.

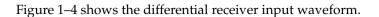
(2) The minimum reconfig_clk frequency is 2.5 MHz if the transceiver channel is configured in **Transmitter Only** mode. The minimum reconfig_clk frequency is 37.5 MHz if the transceiver channel is configured in **Receiver Only** or **Receiver and Transmitter** mode.

- (3) The device cannot tolerate prolonged operation at this absolute maximum.
- (4) The rate matcher supports only up to ±300 parts per million (ppm).
- (5) Supported for the F169 and F324 device packages only.
- (6) Supported for the F484, F672, and F896 device packages only. Pending device characterization.
- (7) To support CDR ppm tolerance greater than ±300 ppm, implement ppm detector in user logic and configure CDR to Manual Lock Mode.
- (8) Asynchronous spread-spectrum clocking is not supported.
- (9) For the EP4CGX30 (F484 package only), EP4CGX50, and EP4CGX75 devices, the CDR ppl tolerance is ±200 ppm.
- (10) Time taken until pll_locked goes high after pll_powerdown deasserts.
- (11) Time that the CDR must be kept in lock-to-reference mode after rx_analogreset deasserts and before rx_locktodata is asserted in manual mode.

(12) Time taken to recover valid data after the rx_locktodata signal is asserted in manual mode (Figure 1–2), or after rx_freqlocked signal goes high in automatic mode (Figure 1–3).

(13) Time taken to recover valid data after the rx_locktodata signal is asserted in manual mode.

- (14) Time taken to recover valid data after the $rx_freqlocked$ signal goes high in automatic mode.
- (15) To support data rates lower than the minimum specification through oversampling, use the CDR in LTR mode only.





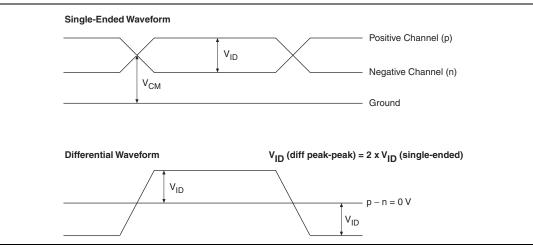


Figure 1–5 shows the transmitter output waveform.



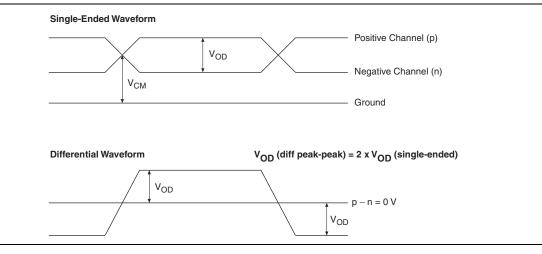


Table 1–22 lists the typical V_{OD} for Tx term that equals 100 Ω .

Table 1–22. Typical V_{0D} Setting, Tx Term = 100 Ω

Symbol		V _{OD} Setting (mV)										
	1	2	3	4 (1)	5	6						
V _{OD} differential peak to peak typical (mV)	400	600	800	900	1000	1200						

Note to Table 1-22:

(1) This setting is required for compliance with the PCIe protocol.

Symbol	Parameter	Min	Тур	Max	Unit
t _{dlock}	Time required to lock dynamically (after switchover, reconfiguring any non-post-scale counters/delays or areset is deasserted)	_	_	1	ms
t _{outjitter_period_dedclk} (6)	Dedicated clock output period jitter $F_{OUT} \ge 100 \text{ MHz}$	_	_	300	ps
	F _{OUT} < 100 MHz	_	—	30	mUI
t _{outjitter_ccj_dedclk} (6)	Dedicated clock output cycle-to-cycle jitter $F_{OUT} \ge 100 \text{ MHz}$	_	_	300	ps
	F _{OUT} < 100 MHz	_	_	30	mUI
t _{outjitter_period_10} (6)	Regular I/O period jitter $F_{OUT} \ge 100 \text{ MHz}$	_	_	650	ps
	F _{OUT} < 100 MHz	—	_	75	mUI
t _{outjitter_ccj_io} <i>(6)</i>	Regular I/O cycle-to-cycle jitter $F_{OUT} \ge 100 \text{ MHz}$	_	_	650	ps
	F _{OUT} < 100 MHz	—	_	75	mUI
t _{PLL_PSERR}	Accuracy of PLL phase shift	—	_	±50	ps
t _{ARESET}	Minimum pulse width on areset signal.	10	_		ns
t _{CONFIGPLL}	Time required to reconfigure scan chains for PLLs	_	3.5 (7)		SCANCLK cycles
f _{scanclk}	scanclk frequency	—	—	100	MHz
t _{casc_outjitter_period_dedclk}	Period jitter for dedicated clock output in cascaded PLLs ($F_{OUT} \ge 100 \text{ MHz}$)	_	_	425	ps
(8), (9)	Period jitter for dedicated clock output in cascaded PLLs ($F_{OUT} < 100 \text{ MHz}$)	_		42.5	mUI

Table 1-25.	PLL Specifications	s for Cyclone IV Devices ^{(1),}	⁽²⁾ (Part 2 of 2)
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Notes to Table 1-25:

- (1) This table is applicable for general purpose PLLs and multipurpose PLLs.
- (2) You must connect $V_{\text{CCD_PLL}}$ to V_{CCINT} through the decoupling capacitor and ferrite bead.
- (3) This parameter is limited in the Quartus II software by the I/O maximum frequency. The maximum I/O frequency is different for each I/O standard.
- (4) The V_{C0} frequency reported by the Quartus II software in the PLL Summary section of the compilation report takes into consideration the V_{C0} post-scale counter K value. Therefore, if the counter K has a value of 2, the frequency reported can be lower than the f_{VC0} specification.
- (5) A high input jitter directly affects the PLL output jitter. To have low PLL output clock jitter, you must provide a clean clock source that is less than 200 ps.
- (6) Peak-to-peak jitter with a probability level of 10⁻¹² (14 sigma, 99.9999999974404% confidence level). The output jitter specification applies to the intrinsic jitter of the PLL when an input jitter of 30 ps is applied.
- (7) With 100-MHz scanclk frequency.

(8) The cascaded PLLs specification is applicable only with the following conditions:

- $\blacksquare \quad Upstream \ PLL 0.59 \ MHz \leq Upstream \ PLL \ bandwidth < 1 \ MHz$
- Downstream PLL—Downstream PLL bandwidth > 2 MHz
- (9) PLL cascading is not supported for transceiver applications.

Symbol	Modes		C6			C 7, I	7		C8, A	7		C8L, I	BL		C9L		Unit
Symbol	WOUCS	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	UIIIL
t _{LOCK} (3)				1	—	—	1	—	_	1		—	1			1	ms

Table 1–31. RSDS Transmitter Timing Specifications for Cyclone IV Devices ^{(1), (2), (4)} (Part 2 of 2)

Notes to Table 1-31:

(1) Applicable for true RSDS and emulated RSDS_E_3R transmitter.

(2) Cyclone IV E devices—true RSDS transmitter is only supported at the output pin of Row I/O Banks 1, 2, 5, and 6. Emulated RSDS transmitter is supported at the output pin of all I/O Banks. Cyclone IV GX devices—true RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated RSDS transmitter is only supported at the

pin of I/O Banks 3, 4, 5, 6, 7, 8, and 9.
(3) t_{LOCK} is the time required for the PLL to lock from the end-of-device configuration.

(4) Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades. Cyclone IV GX devices only support C6, C7, C8, and I7 speed grades.

Gumbal	Madas		C6			C7, 17	,		C8, A7	7	(C8L, 18	SL		C9L		Unit
Symbol	Modes	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	UNIT
	×10	5	—	85	5	—	85	5		85	5		85	5	—	72.5	MHz
	×8	5		85	5		85	5	-	85	5	_	85	5	—	72.5	MHz
f _{HSCLK} (input clock	×7	5	—	85	5	_	85	5	_	85	5	_	85	5	—	72.5	MHz
frequency)	×4	5		85	5		85	5	_	85	5	_	85	5	—	72.5	MHz
,	×2	5	_	85	5	_	85	5		85	5		85	5	_	72.5	MHz
	×1	5	_	170	5	_	170	5	_	170	5	_	170	5	—	145	MHz
	×10	100		170	100		170	100	_	170	100	_	170	100	—	145	Mbps
	×8	80	_	170	80		170	80	_	170	80	_	170	80	—	145	Mbps
Device operation in	×7	70	_	170	70		170	70	_	170	70	_	170	70	—	145	Mbps
Mbps	×4	40	—	170	40	_	170	40	_	170	40	_	170	40	—	145	Mbps
	×2	20	_	170	20		170	20	_	170	20	_	170	20	—	145	Mbps
	×1	10	_	170	10	_	170	10	_	170	10	_	170	10	—	145	Mbps
t _{DUTY}	—	45	_	55	45	-	55	45	_	55	45	_	55	45	—	55	%
TCCS	—	—	_	200	_		200	_	_	200	_	_	200	_	—	200	ps
Output jitter (peak to peak)	_	_	_	500	_	_	500	_	_	550	_	_	600	_		700	ps
	20-80%,																
t _{RISE}	C _{LOAD} = 5 pF	-	500		_	500		_	500		_	500		_	500	—	ps
t _{FALL}	20 - 80%, C _{LOAD} =	_	500	_	_	500	_	_	500	_	_	500	_	_	500		ps
	5 pF																

Table 1–32. Emulated RSDS_E_1R Transmitter Timing Specifications for Cyclone IV Devices ^{(1), (3)} (Part 1 of 2)

Symbol	Modes		C6			C7, 17			C8, A7	7		C8L, 18	L		C9L		Unit
əyiinui	WIUUES	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
t _{LOCK} (2)	_	—		1		—	1	_		1	—		1		—	1	ms

Table 1–32. Emulated RSDS_E	1R Transmitter Timing	Specifications for C	vclone IV Devices ^{(1), (3)}	(Part 2 of 2)
		• • • • • • • • • • • • • • • • •		(

Notes to Table 1-32:

(1) Emulated RSDS_E_1R transmitter is supported at the output pin of all I/O Banks of Cyclone IV E devices and I/O Banks 3, 4, 5, 6, 7, 8, and 9 of Cyclone IV GX devices.

(2) t_{LOCK} is the time required for the PLL to lock from the end-of-device configuration.

(3) Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades. Cyclone IV GX devices only support C6, C7, C8, and I7 speed grades.

Gumbal	Modes		C6			C7, 17	7		C8, A	7		C8L, I	8L		C9L		Unit
Symbol	woues	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	UIIIL
	×10	5	—	200	5	—	155.5	5	—	155.5	5	_	155.5	5	_	132.5	MHz
	×8	5	_	200	5	—	155.5	5	—	155.5	5	_	155.5	5	_	132.5	MHz
f _{HSCLK} (input clock	×7	5	_	200	5	_	155.5	5	—	155.5	5	_	155.5	5	_	132.5	MHz
frequency)	×4	5	_	200	5	—	155.5	5	—	155.5	5		155.5	5		132.5	MHz
,	×2	5	_	200	5	_	155.5	5	—	155.5	5	_	155.5	5	_	132.5	MHz
	×1	5	_	400	5	_	311	5	—	311	5	_	311	5	_	265	MHz
	×10	100	_	400	100	_	311	100	—	311	100		311	100		265	Mbps
	×8	80	_	400	80	_	311	80	—	311	80	_	311	80	_	265	Mbps
Device operation in	×7	70	_	400	70	—	311	70	—	311	70	_	311	70	—	265	Mbps
Mbps	×4	40	—	400	40	—	311	40	—	311	40	_	311	40	—	265	Mbps
	×2	20		400	20		311	20	_	311	20		311	20	_	265	Mbps
	×1	10	_	400	10	—	311	10		311	10	_	311	10		265	Mbps
t _{DUTY}	—	45	_	55	45	_	55	45	—	55	45		55	45		55	%
TCCS	—	_	_	200	_	_	200	_	—	200	_	_	200	_	_	200	ps
Output jitter (peak to peak)	_	_	_	500	_	_	500	_		550	_	_	600		_	700	ps
t _{RISE}	20 - 80%, C _{LOAD} = 5 pF	_	500	_	_	500	_	_	500	_	_	500	_	_	500	_	ps
t _{FALL}	20 - 80%, C _{LOAD} = 5 pF	_	500	_	_	500	_	_	500	_	_	500	_	_	500	_	ps
t _{LOCK} (3)				1			1			1			1			1	ms

Table 1–33. Mini-LVDS Transmitter Timing Specifications for Cyclone IV Devices (1), (2), (4)

Notes to Table 1-33:

(1) Applicable for true and emulated mini-LVDS transmitter.

(2) Cyclone IV E—true mini-LVDS transmitter is only supported at the output pin of Row I/O Banks 1, 2, 5, and 6. Emulated mini-LVDS transmitter is supported at the output pin of all I/O banks.
Cyclone IV GY—true mini-LVDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated mini-LVDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated mini-LVDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated mini-LVDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated mini-LVDS transmitter is supported at the output pin of Row I/O Banks 5 and 6. Emulated mini-LVDS transmitter is supported at the output pin of Row I/O Banks 5.

Cyclone IV GX—true mini-LVDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6. Emulated mini-LVDS transmitter is supported at the output pin of I/O Banks 3, 4, 5, 6, 7, 8, and 9.

(3) t_{LOCK} is the time required for the PLL to lock from the end-of-device configuration.

(4) Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades. Cyclone IV GX devices only support C6, C7, C8, and I7 speed grades.

Gumbal	Modes	C	6	C 7	, 17	C 8,	, A7	C8L	, 18L	C	9L	11
Symbol	woaes	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
	×10	5	420	5	370	5	320	5	320	5	250	MHz
	×8	5	420	5	370	5	320	5	320	5	250	MHz
f _{HSCLK} (input	×7	5	420	5	370	5	320	5	320	5	250	MHz
clock frequency)	×4	5	420	5	370	5	320	5	320	5	250	MHz
	×2	5	420	5	370	5	320	5	320	5	250	MHz
	×1	5	420	5	402.5	5	402.5	5	362	5	265	MHz
	×10	100	840	100	740	100	640	100	640	100	500	Mbps
	×8	80	840	80	740	80	640	80	640	80	500	Mbps
	×7	70	840	70	740	70	640	70	640	70	500	Mbps
HSIODR	×4	40	840	40	740	40	640	40	640	40	500	Mbps
	×2	20	840	20	740	20	640	20	640	20	500	Mbps
	×1	10	420	10	402.5	10	402.5	10	362	10	265	Mbps
t _{DUTY}	—	45	55	45	55	45	55	45	55	45	55	%
TCCS	—	_	200	_	200	—	200		200	—	200	ps
Output jitter (peak to peak)	_	_	500	_	500	_	550		600	_	700	ps
t _{LOCK} (2)	—	—	1	—	1		1	—	1	—	1	ms

Table 1–34. True LVDS Transmitter Timing Specifications for Cyclone IV Devices ^{(1), (3)}

Notes to Table 1-34:

(1) Cyclone IV E—true LVDS transmitter is only supported at the output pin of Row I/O Banks 1, 2, 5, and 6. Cyclone IV GX—true LVDS transmitter is only supported at the output pin of Row I/O Banks 5 and 6.

(2) t_{LOCK} is the time required for the PLL to lock from the end-of-device configuration.

(3) Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades. Cyclone IV GX devices only support C6, C7, C8, and I7 speed grades.

Table 1–35. Emulated LVDS Transmitter Timing Specifications for Cyclone IV Devices ^{(1), (3)} (Part 1 of 2)

Gumbal	Madaa	C	6	C7,	, 17	C8,	A7	C8L	, 18L	C	9L	Unit
Symbol	Modes	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
	×10	5	320	5	320	5	275	5	275	5	250	MHz
	×8	5	320	5	320	5	275	5	275	5	250	MHz
f _{HSCLK} (input clock	×7	5	320	5	320	5	275	5	275	5	250	MHz
frequency)	×4	5	320	5	320	5	275	5	275	5	250	MHz
1 37	×2	5	320	5	320	5	275	5	275	5	250	MHz
	×1	5	402.5	5	402.5	5	402.5	5	362	5	265	MHz
	×10	100	640	100	640	100	550	100	550	100	500	Mbps
	×8	80	640	80	640	80	550	80	550	80	500	Mbps
HSIODR	×7	70	640	70	640	70	550	70	550	70	500	Mbps
HOIDDA	×4	40	640	40	640	40	550	40	550	40	500	Mbps
	×2	20	640	20	640	20	550	20	550	20	500	Mbps
	×1	10	402.5	10	402.5	10	402.5	10	362	10	265	Mbps

• For more information about the supported maximum clock rate, device and pin planning, IP implementation, and device termination, refer to *Section III: System Performance Specifications* of the *External Memory Interface Handbook*.

Table 1–37 lists the memory output clock jitter specifications for Cyclone IV devices.

Table 1–37. Memory Output Clock Jitter Specifications for Cyclone IV Devices (1), (2)

Parameter	Symbol	Min	Max	Unit
Clock period jitter	t _{JIT(per)}	-125	125	ps
Cycle-to-cycle period jitter	t _{JIT(cc)}	-200	200	ps
Duty cycle jitter	t _{JIT(duty)}	-150	150	ps

Notes to Table 1-37:

(1) Memory output clock jitter measurements are for 200 consecutive clock cycles, as specified in the JEDEC DDR2 standard.

(2) The clock jitter specification applies to memory output clock pins generated using DDIO circuits clocked by a PLL output routed on a global clock (GCLK) network.

Duty Cycle Distortion Specifications

Table 1–38 lists the worst case duty cycle distortion for Cyclone IV devices.

Table 1–38. Duty Cycle Distortion on Cyclone IV Devices I/O Pins (1), (2), (3)

Symbol	C	6	C7	, 17	C8, I8	BL, A7	C	9L	Unit
Symbol	Min	Max	Min	Max	Min	Max	Min	Max	UIIIL
Output Duty Cycle	45	55	45	55	45	55	45	55	%

Notes to Table 1-38:

(1) The duty cycle distortion specification applies to clock outputs from the PLLs, global clock tree, and IOE driving the dedicated and general purpose I/O pins.

(2) Cyclone IV devices meet the specified duty cycle distortion at the maximum output toggle rate for each combination of I/O standard and current strength.

(3) Cyclone IV E 1.0 V core voltage devices only support C8L, C9L, and I8L speed grades. Cyclone IV E 1.2 V core voltage devices only support C6, C7, C8, I7, and A7 speed grades. Cyclone IV GX devices only support C6, C7, C8, and I7 speed grades.

OCT Calibration Timing Specification

Table 1–39 lists the duration of calibration for series OCT with calibration at device power-up for Cyclone IV devices.

Table 1–39. Timing Specification for Series OCT with Calibration at Device Power-Up for Cyclone IV Devices $^{(1)}$

Symbol	Description	Maximum	Units	
t _{octcal}	Duration of series OCT with calibration at device power-up	20	μs	

Note to Table 1-39:

(1) OCT calibration takes place after device configuration and before entering user mode.

I/O Timing

Use the following methods to determine I/O timing:

- the Excel-based I/O Timing
- the Quartus II timing analyzer

The Excel-based I/O timing provides pin timing performance for each device density and speed grade. The data is typically used prior to designing the FPGA to get a timing budget estimation as part of the link timing analysis. The Quartus II timing analyzer provides a more accurate and precise I/O timing data based on the specifics of the design after place-and-route is complete.

The Excel-based I/O Timing spreadsheet is downloadable from Cyclone IV Devices Literature website.

Glossary

Table 1–46 lists the glossary for this chapter.

Letter	Term	Definitions
Α	—	—
В		—
C	—	—
D	_	—
E	_	—
F	f _{HSCLK}	High-speed I/O block: High-speed receiver/transmitter input and output clock frequency.
G	GCLK	Input pin directly to Global Clock network.
u	GCLK PLL	Input pin to Global Clock network through the PLL.
Н	HSIODR	High-speed I/O block: Maximum/minimum LVDS data transfer rate (HSIODR = 1/TUI).
I	Input Waveforms for the SSTL Differential I/O Standard	Vswing Vswing V _{IH} V _{REF} V _{IL}

Table 1-46. Glossary (Part 1 of 5)

Table 1-46. Glossary (Part 5 of 5)

Letter	Term	Definitions
	V _{CM(DC)}	DC common mode input voltage.
	V _{DIF(AC)}	AC differential input voltage: The minimum AC input differential voltage required for switching.
	V _{DIF(DC)}	DC differential input voltage: The minimum DC input differential voltage required for switching.
	V _{ICM}	Input common mode voltage: The common mode of the differential signal at the receiver.
	V _{ID}	Input differential voltage swing: The difference in voltage between the positive and complementary conductors of a differential transmission at the receiver.
	V _{IH}	Voltage input high: The minimum positive voltage applied to the input that is accepted by the device as a logic high.
	V _{IH(AC)}	High-level AC input voltage.
	V _{IH(DC)}	High-level DC input voltage.
	V _{IL}	Voltage input low: The maximum positive voltage applied to the input that is accepted by the device as a logic low.
	V _{IL (AC)}	Low-level AC input voltage.
	V _{IL (DC)}	Low-level DC input voltage.
	V _{IN}	DC input voltage.
	V _{OCM}	Output common mode voltage: The common mode of the differential signal at the transmitter.
V	V _{OD}	Output differential voltage swing: The difference in voltage between the positive and complementary conductors of a differential transmission at the transmitter. $V_{0D} = V_{0H} - V_{0L}$.
	V _{OH}	Voltage output high: The maximum positive voltage from an output that the device considers is accepted as the minimum positive high level.
	V _{OL}	Voltage output low: The maximum positive voltage from an output that the device considers is accepted as the maximum positive low level.
	V _{os}	Output offset voltage: $V_{OS} = (V_{OH} + V_{OL}) / 2$.
	V _{OX (AC)}	AC differential output cross point voltage: the voltage at which the differential output signals must cross.
	V _{REF}	Reference voltage for the SSTL and HSTL I/O standards.
	V _{REF (AC)}	AC input reference voltage for the SSTL and HSTL I/O standards. $V_{REF(AC)} = V_{REF(DC)} + noise$. The peak-to-peak AC noise on V_{REF} must not exceed 2% of $V_{REF(DC)}$.
	V _{REF (DC)}	DC input reference voltage for the SSTL and HSTL I/O standards.
	V _{SWING (AC)}	AC differential input voltage: AC input differential voltage required for switching. For the SSTL differential I/O standard, refer to Input Waveforms.
	V _{SWING (DC)}	DC differential input voltage: DC input differential voltage required for switching. For the SSTL differential I/O standard, refer to Input Waveforms.
	V _{TT}	Termination voltage for the SSTL and HSTL I/O standards.
	V _{X (AC)}	AC differential input cross point voltage: The voltage at which the differential input signals must cross.
W	—	_
X	—	—
Y	—	_
Z	—	_

Document Revision History

Table 1–47 lists the revision history for this chapter.

Date	Version	Changes
March 2016	2.0	Updated note (5) in Table 1–21 to remove support for the N148 package.
Ostobor 2014	1.9	Updated maximum value for V _{CCD_PLL} in Table 1–1.
October 2014		Removed extended temperature note in Table 1–3.
December 2013	1.8	Updated Table 1–21 by adding Note (15).
May 2013	1.7	Updated Table 1–15 by adding Note (4).
	1.6	■ Updated the maximum value for V _I , V _{CCD_PLL} , V _{CCI0} , V _{CC_CLKIN} , V _{CCH_GXB} , and V _{CCA_GXB} Table 1–1.
		■ Updated Table 1–11 and Table 1–22.
October 2012		 Updated Table 1–21 to include peak-to-peak differential input voltage for the Cyclone IV GX transceiver input reference clock.
		■ Updated Table 1–29 to include the typical DCLK value.
		 Updated the minimum f_{HSCLK} value in Table 1–31, Table 1–32, Table 1–33, Table 1–34, and Table 1–35.
	1.5	 Updated "Maximum Allowed Overshoot or Undershoot Voltage", "Operating Conditions", and "PLL Specifications" sections.
November 2011		 Updated Table 1–2, Table 1–3, Table 1–4, Table 1–5, Table 1–8, Table 1–9, Table 1–15, Table 1–18, Table 1–19, and Table 1–21.
		■ Updated Figure 1–1.
	1.4	 Updated for the Quartus II software version 10.1 release.
December 2010		■ Updated Table 1–21 and Table 1–25.
		 Minor text edits.
	1.3	Updated for the Quartus II software version 10.0 release:
		■ Updated Table 1–3, Table 1–4, Table 1–21, Table 1–25, Table 1–28, Table 1–30, Table 1–40, Table 1–41, Table 1–42, Table 1–43, Table 1–44, and Table 1–45.
July 2010		■ Updated Figure 1–2 and Figure 1–3.
		 Removed SW Requirement and TCCS for Cyclone IV Devices tables.
		 Minor text edits.
	1.2	Updated to include automotive devices:
		 Updated the "Operating Conditions" and "PLL Specifications" sections.
March 2010		 Updated Table 1–1, Table 1–8, Table 1–9, Table 1–21, Table 1–26, Table 1–27, Table 1–31, Table 1–32, Table 1–33, Table 1–34, Table 1–35, Table 1–36, Table 1–37, Table 1–38, Table 1–40, Table 1–42, and Table 1–43.
		 Added Table 1–5 to include ESD for Cyclone IV devices GPIOs and HSSI I/Os.
		 Added Table 1–44 and Table 1–45 to include IOE programmable delay for Cyclone IV E 1.2 V core voltage devices.
		 Minor text edits.

Table 1–47. Document Revision History

Date	Version	Changes
February 2010	1.1	 Updated Table 1–3 through Table 1–44 to include information for Cyclone IV E devices and Cyclone IV GX devices for Quartus II software version 9.1 SP1 release. Minor text edits.
November 2009	1.0	Initial release.